



FZT657

300V NPN MEDIUM POWER HIGH VOLTAGE TRANSISTOR IN SOT223

Features

- BV_{CEO} > 300V
- BV_{CBO} > 300V
- I_C = 0.5A High Continuous Current
- I_{CM} = 1A Peak Pulse Current
- Complementary PNP Type: FZT757
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

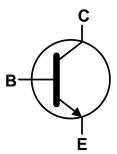
Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound;
 UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.112 grams (Approximate)

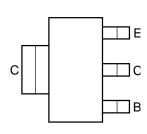




Top View



Device Symbol



Top View Pin-Out

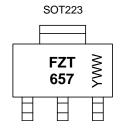
Ordering Information (Note 5)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
FZT657TA	AEC-Q101	FZT657	7	12	1,000
FZT657QTA	Automotive	FZT657	7	12	1,000

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to https://www.diodes.com/quality/.
- 5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information



FZT 657 = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 8 = 2018) WW or $\overline{W}W$ = Week Code (01 to 53)



Absolute Maximum Ratings ($@T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	300	V
Collector-Emitter Voltage	$V_{\sf CEO}$	300	V
Emitter-Base Voltage	V_{EBO}	7	V
Continuous Collector Current	lc	0.5	Α
Peak Pulse Current	I _{CM}	1	Α

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 6)		3.0		
Rower Dissipation	(Note 7)	Ь	2.0	W	
Power Dissipation	(Note 8)		1.6	VV	
	(Note 9)		1.2		
	(Note 6)		41.7		
Thermal Desistance, lunction to Ambient	(Note 7)	$R_{ hetaJA}$	62.5		
Thermal Resistance, Junction to Ambient	(Note 8)		78.1	°C/W	
	(Note 9)		104	1	
Thermal Resistance Junction to Lead (Note 10)		$R_{ hetaJL}$	12.9		
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C		

ESD Ratings (Note 11)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

- 6. For a device mounted with the collector lead on 50mm x 50mm 2oz copper that is on a single-sided 1.6mm FR-4 PCB; device is measured under 6. For a device mounted with the collector lead on 50mm x 50mm 2oz copper that is on a still air conditions whilst operating in a steady-state.

 7. Same as Note 6, except the device is mounted on 25mm x 25mm 2oz copper.

 8. Same as Note 6, except the device is mounted on 25mm x 25mm 1oz copper.

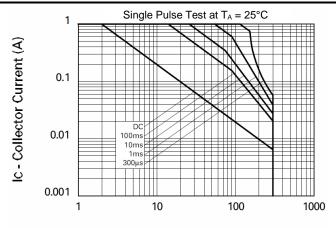
 9. Same as Note 6, except the device is mounted on minimum recommended pad layout.

 10. Thermal resistance from junction to solder-point (at the end of the collector lead).

 11. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

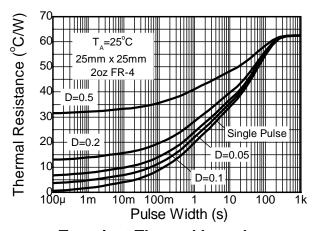


Thermal Characteristics and Derating Information

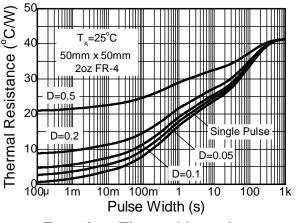


VCE - Collector Emitter Voltage (V)

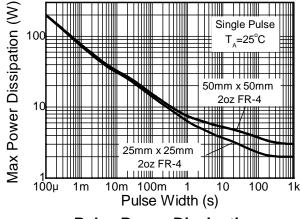
Safe Operating Area



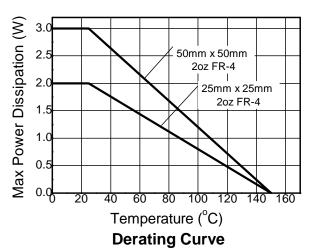
Transient Thermal Impedance



Transient Thermal Impedance



Pulse Power Dissipation





Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

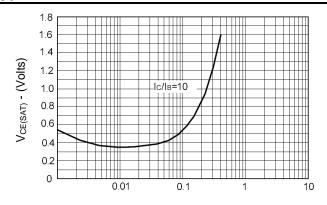
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	300	_	_	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 12)	BV _{CEO}	300	_	_	V	I _C = 10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	7	_	_	V	I _E = 100μA
Collector-Base Cut-Off Current	I _{CBO}	_	_	100	nA	V _{CB} = 200V
Emitter Cut-Off Current	I _{EBO}	_	_	100	nA	V _{EB} = 5.6V
DC Current Gain (Note 12)	h _{FE}	40 50	_	_	_	$I_C = 10 \text{mA}, V_{CE} = 5 \text{V}$ $I_C = 100 \text{mA}, V_{CE} = 5 \text{V}$
Collector-Emitter Saturation Voltage (Note 12)	V _{CE(SAT)}	_	_	0.5	V	I _C = 100mA, I _B = 10mA
Base-Emitter Saturation Voltage (Note 12)	V _{BE(SAT)}	_	_	1.0	V	I _C = 100mA, I _B = 10mA
Base-Emitter Turn-On Voltage (Note 12)	V _{BE(ON)}	_	_	1.0	V	I _C = 100mA, V _{CE} = 5V
Output Capacitance	C _{OBO}	_	_	20	pF	$V_{CB} = 20V, f = 1MHz$
Current Gain-Bandwidth Product	f _T	30	_	_	MHz	V _{CE} = 20V, I _C = 10mA, f = 20MHz

Note:

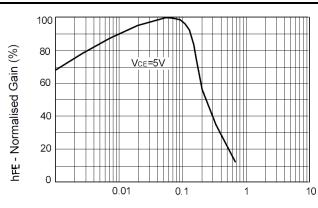
12. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



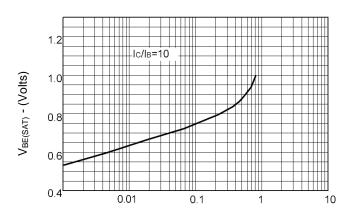
Ic - Collector Current (Amps)



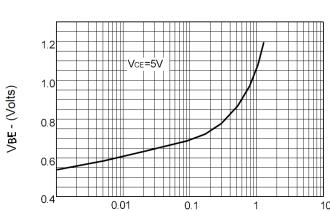
Ic - Collector Current (Amps)

hfe v IC

V_{CE(SAT)} v I_C

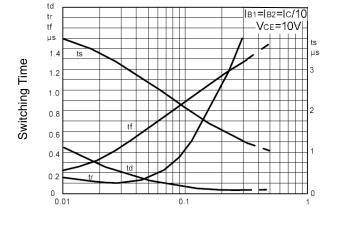


Ic - Collector Current (Amps)

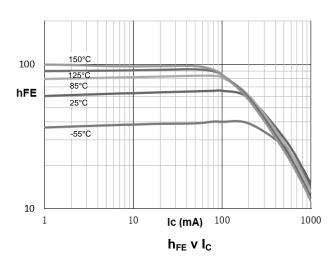


I_C - Collector Current (Amps) $V_{BE(ON)} v I_{C}$

V_{BE(SAT)} v I_C



Ic - Collector Current (Amps)



Switching Speeds

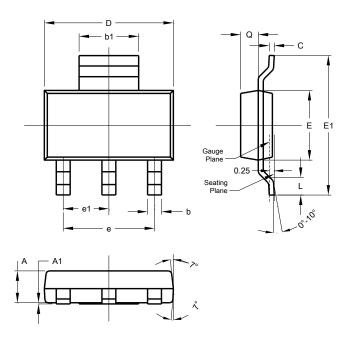
10



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223

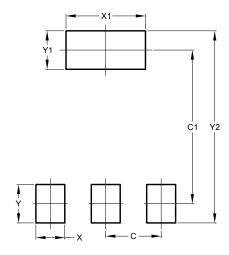


SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b	0.60	0.80	0.70		
b1	2.90	3.10	3.00		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
Е	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е	-	-	4.60		
e1	-	-	2.30		
L	0.85	1.05	0.95		
Q	0.84	0.94	0.89		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223



Dimensions	Value (in mm)
С	2.30
C1	6.40
X	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device terminals and PCB tracking.



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